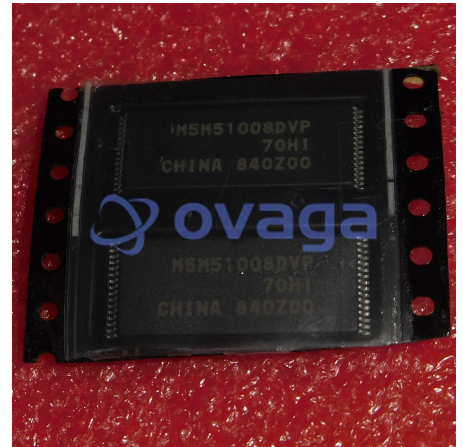


Low Power SRAM; Organization (word): 128K; Organization (bit): x 8; Memory capacity (bit): 1M; Access time (ns): 70; Supply voltage (V): 4.5 to 5.5; Operating temperature (°C): 0 to 70; Package: TSOP (32)



Images are for reference only

Manufacturers	Renesas Technology Corp
Package/Case	TSOP32
Product Type	Integrated Circuits (ICs)
RoHS	
Lifecycle	

Please submit RFQ for M5M51008DVP-70H or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

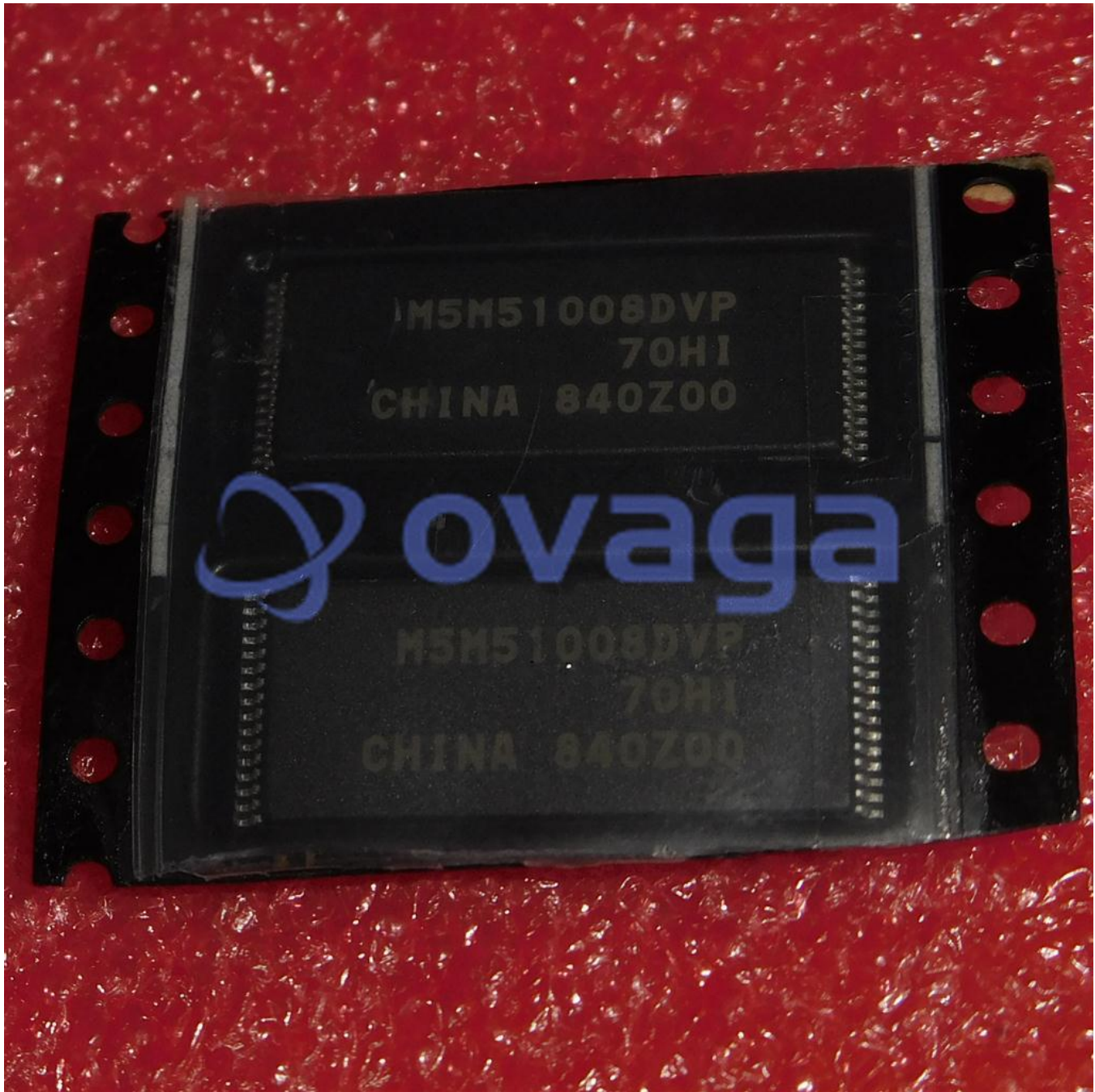
M5M51008DVP-70H is a type of Static Random Access Memory (SRAM) integrated circuit (IC) manufactured by Mitsubishi Electric Corporation.

Features

- 1 Megabit (128K x 8) of memory
- Access time of 70 nanoseconds
- Single +5V power supply
- Low power consumption
- Non-volatile memory cells

Application

- AS7C31026B-70JC
- CY7C1041CV33-15ZCT
- HM628128ALP-7
- IS61C1024AL-12JLI
- K6R1016C1C-JC10
- MB81C1000A-70PSZ
- TC55VCM316ATGN-70



Related Products



[M51958BFP](#)

Renesas Technology Corp
SOP-20



[M5M51008DFP-70H](#)

Renesas Technology Corp
SOP-32



[M51995AFP#CF0J](#)

Renesas Technology Corp
SOP-20



[M51957BFP](#)

Renesas Technology Corp
SOP-8



[M5M51008DFP-55HIBT](#)

Renesas Technology Corp
SOP-32



[M5M5V108DVP-70H](#)

Renesas Technology Corp
TSSOP32



[M5223AFP](#)

Renesas Technology Corp
SOP-8



[M51995AP#TF0J](#)

Renesas Technology Corp
DIP